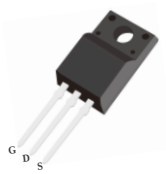
MPVX20N50B Series
Power MOSFET

FEATURES

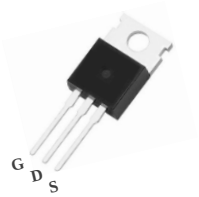
- BV_{DSS}: 500V, I_D=20A
- $R_{DS(on)}$: 0.3Ω(Max) @V_{GS}=10V
- Very Low FOM ($R_{DS(on)}$ *Q_g)
- Excellent stability and uniformity

APPLICATIONS

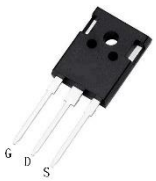
- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Power Factor Correction (PFC)
- AC to DC Converters



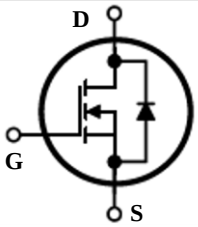
TO-220F



TO-220



TO-247



Ordering Information

Type NO.	Marking	Package Code
MPVA20N50B	MPVA20N50B	TO-220F
MPVP20N50B	MPVP20N50B	TO-220
MPVW20N50B	MPVW20N50B	TO-247

Absolute Maximum Ratings T_C = 25ºC, unless otherwise noted

Parameter		Symbol	Value		Unit
			220F	220-247	
Drain-Source Voltage (V_{GS} = 0V)		V_{DSS}	500		V
Continuous Drain Current		I_D	20		A
Pulsed Drain Current	(note1)	I_{DM}	72		A
Gate-Source Voltage		V_{GSS}	±30		V
Single Pulse Avalanche Energy	(note2)	E_{AS}	1000		mJ
Avalanche Current	(note1)	I_{AR}	12		A
Repetitive Avalanche Energy	(note1)	E_{AR}	64		mJ
Power Dissipation (T_C = 25ºC)		P_D	98	210	W
Operating Junction and Storage Temperature Range		T_J, T_{stg}	-55~+150		ºC

Thermal Resistance

Parameter	Symbol	Value		Unit
		220F	220-247	
Thermal Resistance, Junction-to-Case	R_{thJC}	1.27	0.6	ºC/W
Thermal Resistance, Junction-to-Ambient	R_{thJA}	62.5	60.0	

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Specifications T_J = 25ºC, unless otherwise noted						
Parameter	**Symbol**	**Test Conditions**	**Value**			**Unit**
			Min.	**Typ.**	**Max.**	
Static						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	V_{GS} = 0V, I_D = 250μA	500	--	--	V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = 500V, V_{GS} = 0V, T_J = 25ºC	--	--	1	μA
Gate-Source Leakage	I_{GSS}	V_{GS} = ±30V	--	--	±100	nA
Gate-Source Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250μA	3.0	--	4.0	V
Drain-Source On-Resistance (Note4)	$R_{DS(on)}$	V_{GS} = 10V, I_D = 10.0A	--	0.24	0.30	Ω
Dynamic						
Input Capacitance	C_{iss}	V_{GS} = 0V, V_{DS} = 25V, f = 1.0MHz	--	3000	--	pF
Output Capacitance	C_{oss}		--	221	--	
Reverse Transfer Capacitance	C_{rss}		--	16	--	
Total Gate Charge	Q_g	V_{DD} = 400V, I_D = 20.0A, V_{GS} = 10V	--	75	--	nC
Gate-Source Charge	Q_{gs}		--	10	--	
Gate-Drain Charge	Q_{gd}		--	31	--	
Turn-on Delay Time	$t_{d(on)}$	V_{DD} =250V, I_D = 20.0A, R_G = 25Ω	--	35	--	ns
Turn-on Rise Time	t_r		--	40	--	
Turn-off Delay Time	$t_{d(off)}$		--	160	--	
Turn-off Fall Time	t_f		--	55	--	
Drain-Source Body Diode Characteristics						
Continuous Body Diode Current	I_S	T_C = 25ºC	--	--	20	A
Pulsed Diode Forward Current	I_{SM}		--	--	80	
Body Diode Voltage	V_{SD}	T_J = 25ºC, I_{SD} = 20.0A, V_{GS} = 0V	--	--	1.4	V
Reverse Recovery Time	t_{rr}	V_{GS} = 0V, I_F = 20.0A, di_F/dt = 100A/μs	--	430	--	ns
Reverse Recovery Charge	Q_{rr}		--	6.5	--	μC

Notes

1. Repetitive Rating: Pulse width limited by maximum junction temperature
2. I_{AS} = 12A, V_{DD} = 50V, R_G = 25Ω, Starting T_J = 25°C
3. Pulse Test: Pulse width ≤ 300μs, Duty Cycle ≤ 1%
4. Essentially independent of operating temperature

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Typical Characteristics T_J = 25ºC, unless otherwise noted

Figure 1. Output Characteristics

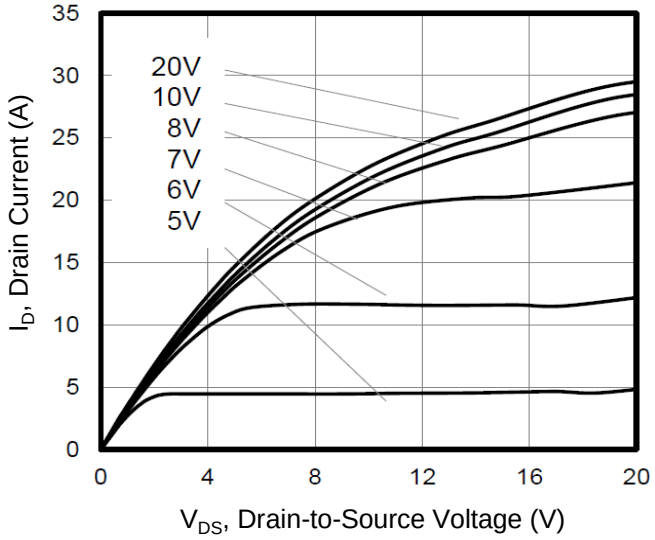


Figure 2. Transfer Characteristics

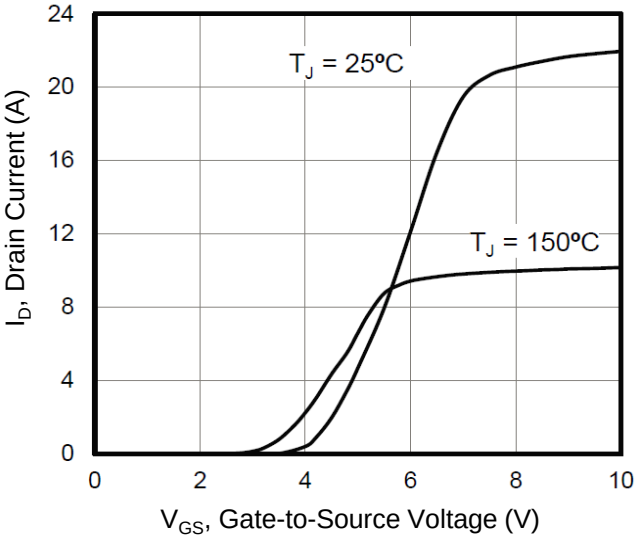


Figure 3. Drain Current vs. Temperature

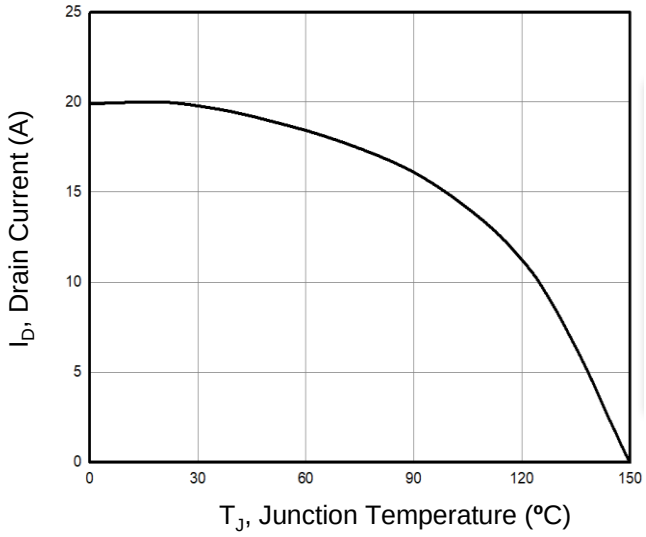


Figure 4. Capacitance

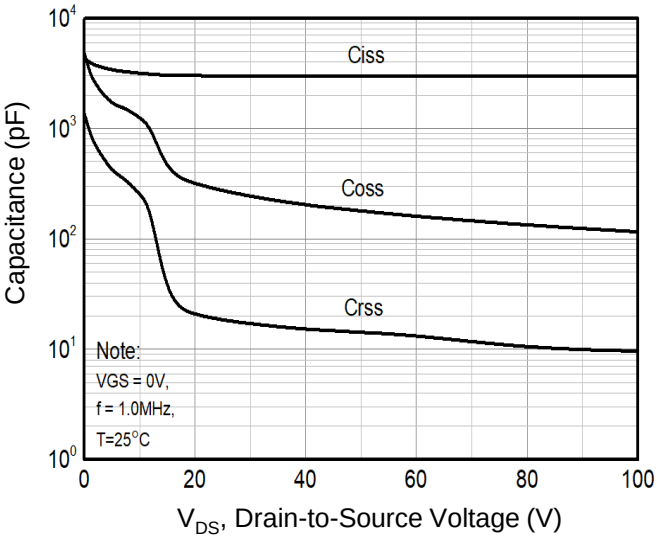


Figure 5. Gate Charge

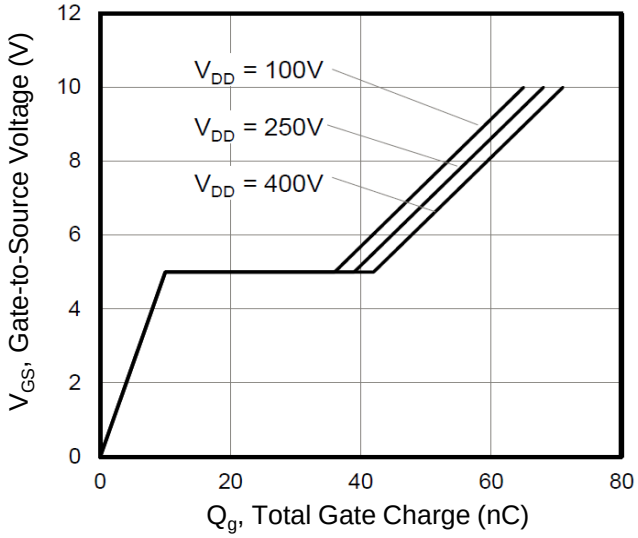
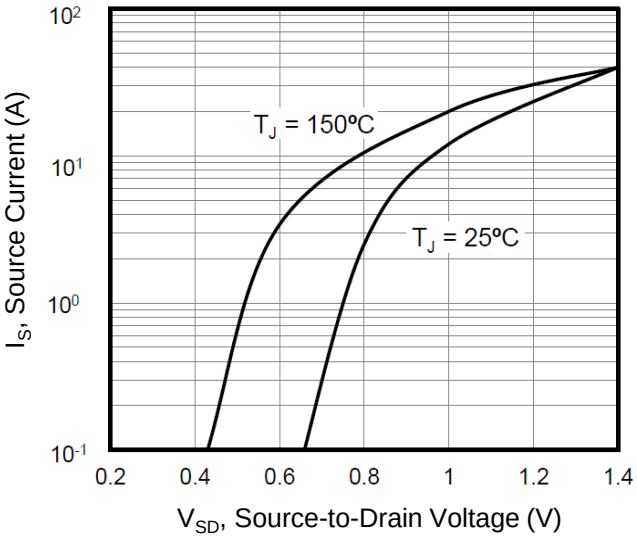


Figure 6. Body Diode Forward Voltage



Typical Characteristics T_J = 25ºC, unless otherwise noted

Figure 7. On-Resistance vs. Temperature

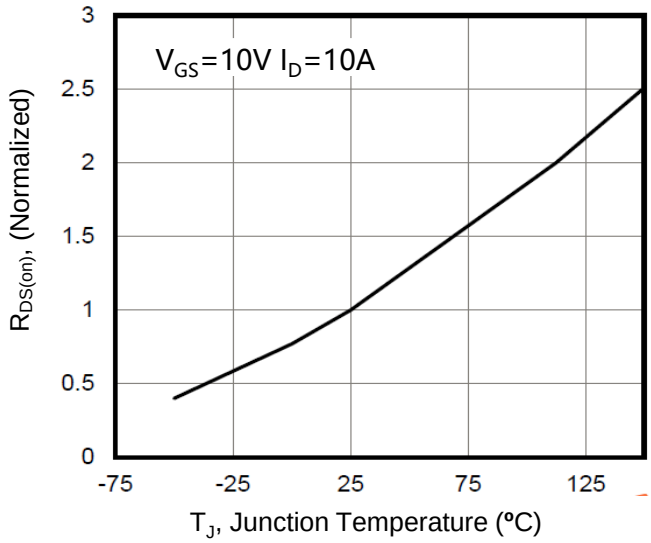


Figure 8. BV_{DSS} vs. Temperature

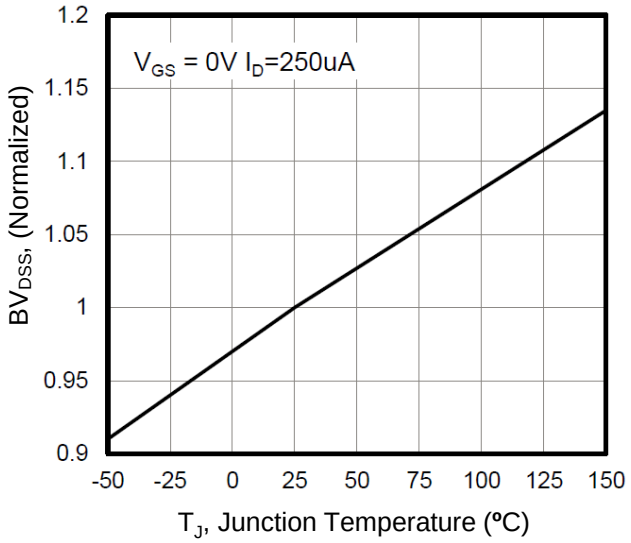


Figure 9. Transient Thermal Impedance (TO-220F)

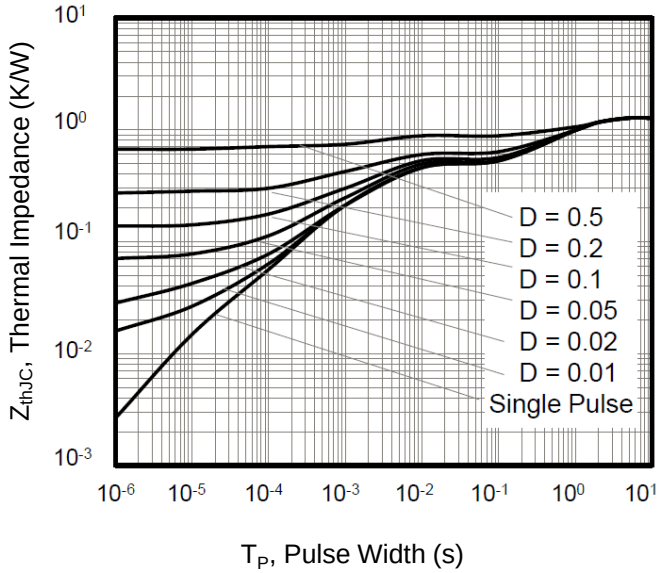


Figure 10. Transient Thermal Impedance (TO-220 TO-247)

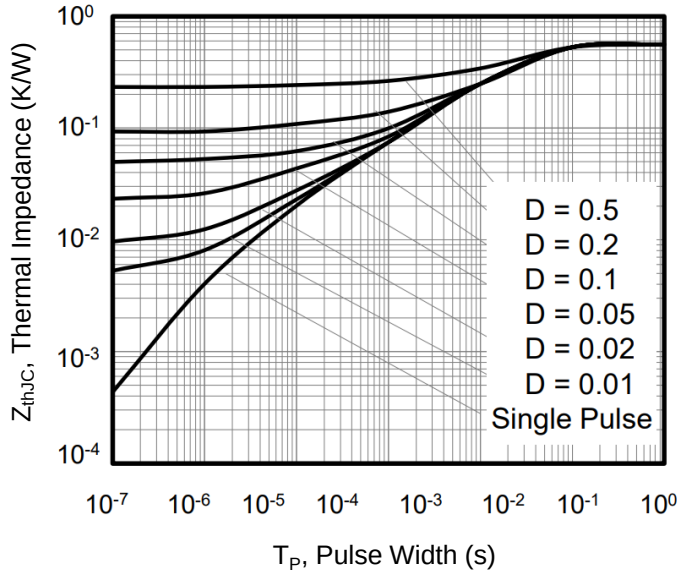


Figure A：Gate Charge Test Circuit and Waveform

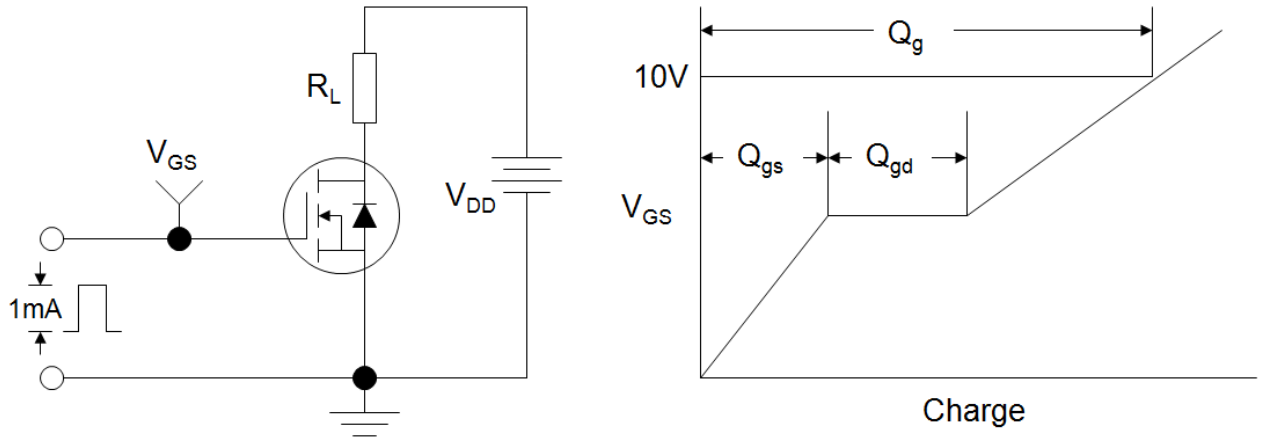


Figure B：Resistive Switching Test Circuit and Waveform

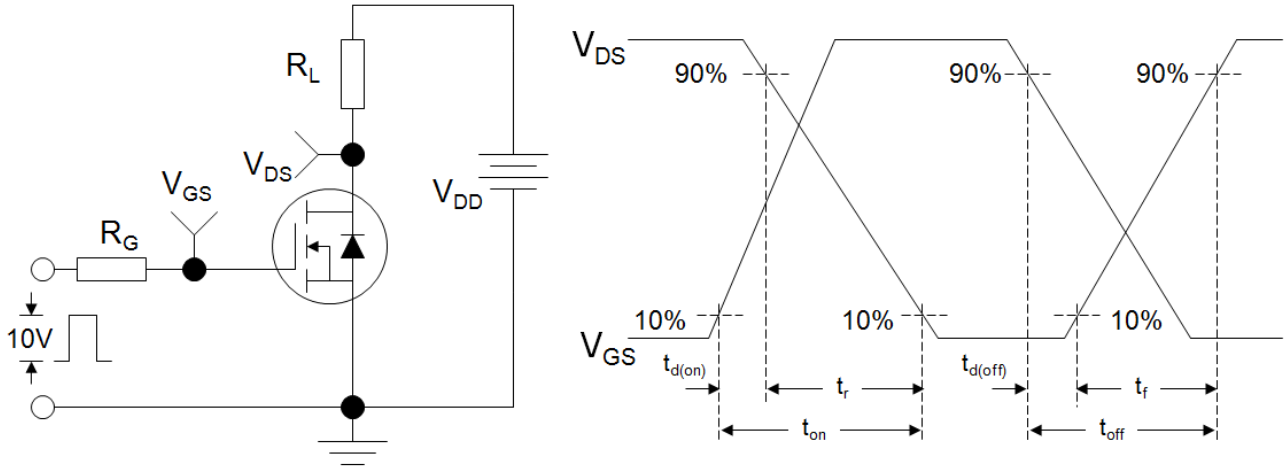
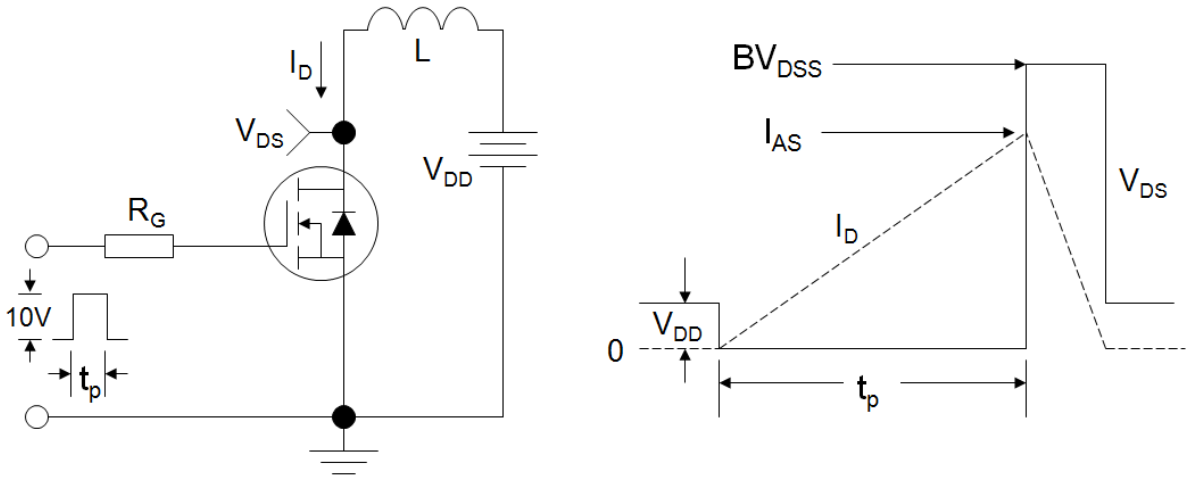


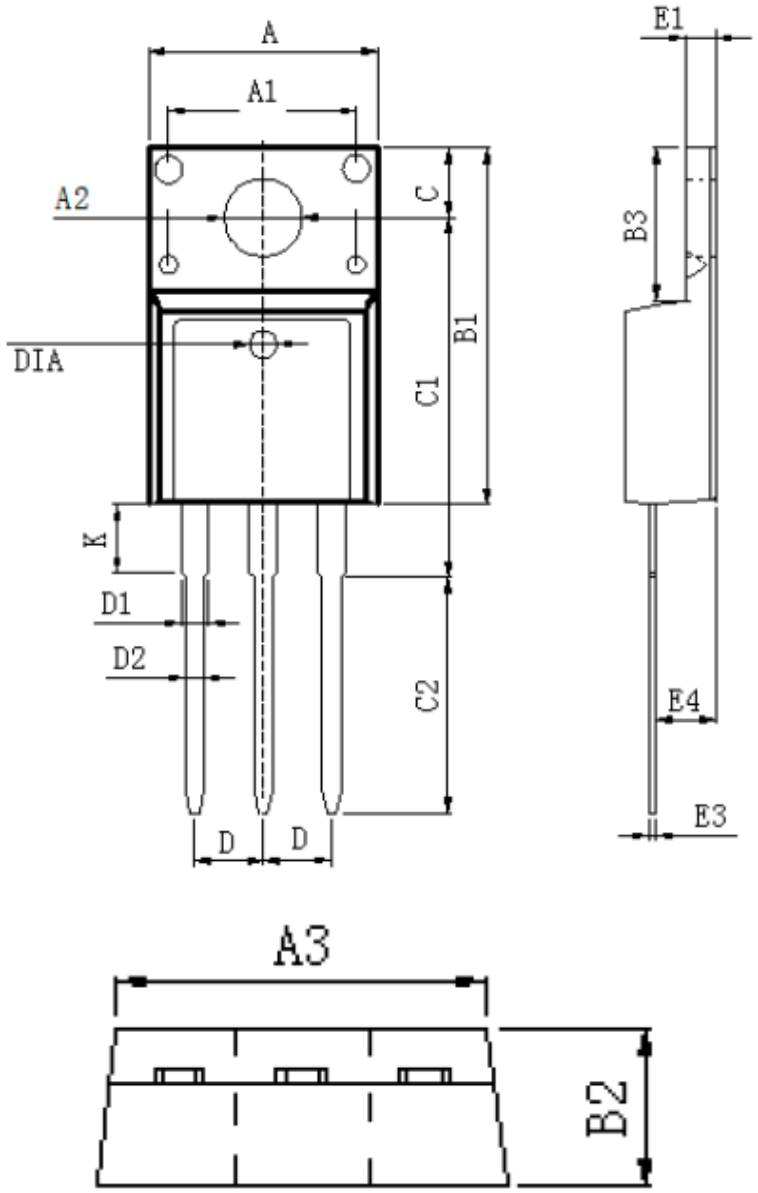
Figure C：Unclamped Inductive Switching Test Circuit and Waveform



Outline Dimension

Unit: mm

TO-220F



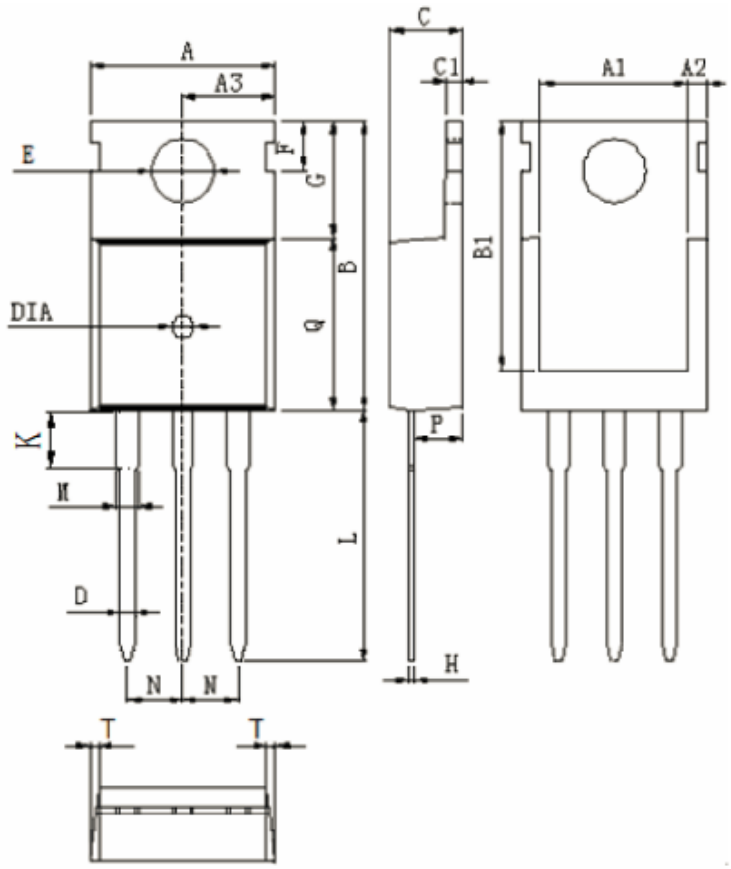
DIM	MILLIMETERS
A	10. 16±0. 3
A1	7. 00±0. 1
A2	3. 3±0. 2
A3	9. 5±0. 2
B1	15. 87±0. 3
B2	4. 7±0. 2
B3	6. 68±0. 4
C	3. 3±0. 2
C1	12. 57±0. 3
C2	10. 02±0. 5
D	2. 54±0. 05
D1	1. 28±0. 2
D2	0. 8±0. 1
K	3. 1±0. 3
E1	2. 54±0. 1
E3	0. 5±0. 1
E4	2. 76±0. 2
DIA	⊙1. 5(deep 0. 2)

Unit :mm

Outline Dimension

Unit: mm

TO-220



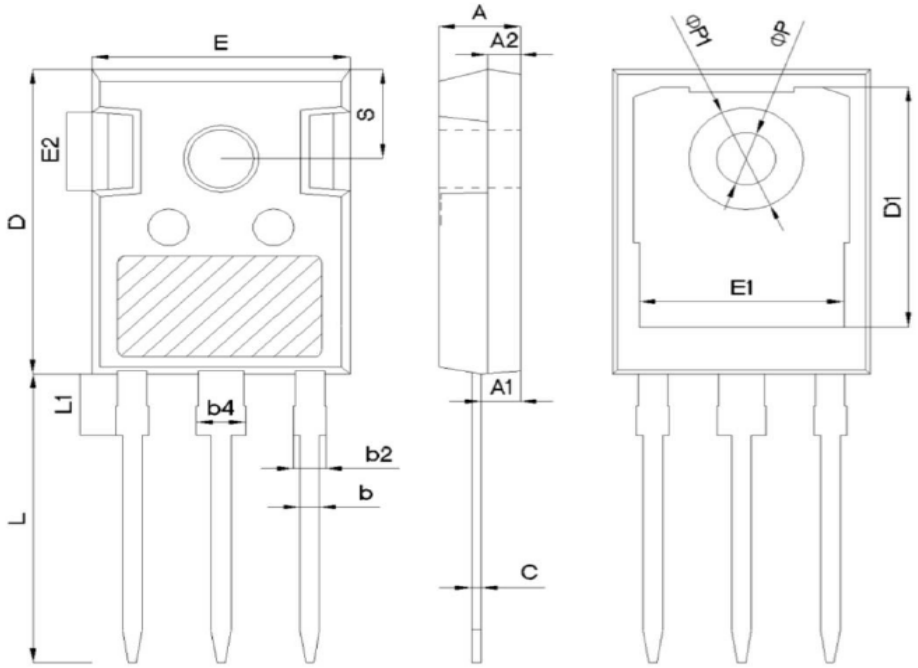
DIM	MILLIMETERS
A	10.0±0.3
A1	8.64±0.2
A2	1.15±0.1
A3	5.0±0.2
B	15.8±0.4
B1	13.2±0.3
C	4.56±0.1
C1	1.3±0.2
D	0.8±0.2
E	3.6±0.2
F	2.95±0.3
G	6.5±0.3
H	0.5±0.1
K	3.1±0.2
L	13.2±0.4
M	1.25±0.1
N	2.54±0.1
P	2.4±0.3
Q	9.0±0.3
T	W:0.35
DIA	⊙1.5(deep 0.2)

Unit :mm

Outline Dimension

Unit: mm

TO-247



SYMBOL	mm		
	MIN	NOM	MAX
A	4.80	5.00	5.20
A1	2.21	2.41	2.61
A2	1.85	2.00	2.15
b	1.11	1.21	1.36
b2	1.91	2.01	2.21
b4	2.91	3.01	3.21
c	0.51	0.61	0.75
D	20.70	21.00	21.30
D1	16.25	16.55	16.85
E	15.50	15.80	16.10
E1	13.00	13.30	13.60
E2	4.80	5.00	5.20
E3	2.30	2.50	2.70
e	5.44BSC		
L	19.62	19.92	20.22
L1	-	-	4.30
ΦP	3.40	3.60	3.80
ΦP1	-	-	7.30
S	6.15BSC		

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